NSN 5961-00-825-4627

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-825-4627 **Inclosure Material:** Glass **Overall Length:** 0.250 inches **Terminal Length:** 0.600 inches **Overall Diameter:** 0.095 inches **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 50.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 20.00 amperes forward current, average preset and 1.00 amperes forward current, average absolute **Capacitance Rating In Picofarads:** 150.0 **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Precious Material And Location:** Plated leads gold **Precious Material:** Gold **Test Data Document:** 18323-579r622 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**